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Excitonic interactions and mechanism for ultrafast interlayer photoexcited response in van der Waals heterostructures

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Abstract

Optical dynamics in van der Waals heterobilayers is of fundamental scientific and practical interest. Based on a time-dependent adiabatic GW approach, we discover a new many-electron (excitonic) channel for converting photoexcited intralayer to interlayer excitations and the associated ultrafast optical responses in heterobilayers, which is conceptually different from the conventional single-particle picture. We find strong electron-hole interactions drive the dynamics and enhance the pump-probe optical responses by an order of magnitude with a rise time of ~300 fs in MoSe₂/WSe₂ heterobilayers, in agreement with experiment.

By stacking a variety of two-dimensional (2D) material layers together, van der Waals (vdW) heterostructures offer a novel, versatile platform for exploring fascinating low-dimensional physics, such as Hofstadter butterfly states [1], topological phases [2,3], unconventional superconductors [4], and strong-correlated insulators [5]. Among the diverse 2D materials, the semiconducting monolayer transition metal dichalcogenide (TMD) family has attracted broad interest for photonics and optoelectronics because of their direct band gap properties and strong light-matter interactions [6]. Particularly, many TMD heterobilayers exhibit a type-II band alignment, *i.e.* the conduction band minimum (CBM) and the valence band maximum (VBM) reside in different layers. The type-II alignment provides a rich playground for investigating various optically-induced exciton states (intralayer excitons on the individual layers and interlayer excitons across the two layers), as well as their dynamical evolution from mutual interactions [7-19].

Although recent optical pump-probe spectroscopies have provided rich experimental signatures on the ultrafast optical responses in heterobilayers [7-10], their accurate theoretical description and understanding remain to be fully understood. Most previous experimental interpretations on the interlayer optical dynamics are based on a "single-particle" picture: independent holes or electrons transfer from one monolayer to its neighbor through band hybridization or phonon-assisted scattering [7]. However, such an independent-particle (IP) picture is conceptually insufficient: in atomically thin TMD materials, the electrons and holes are known to be strongly bounded to form two-particle low energy states, *i.e.* excitons (correlated electron-hole pairs) with giant binding energy, due to enhanced Coulomb interaction from low-dimensional quantum confinement and reduced dielectric screening [6,20]. A vast literature of previous studies has shown that the IP picture can not describe most optically-induced phenomena even qualitatively in low-dimensional systems [20-26]. Therefore, a many-electron picture including electron-hole interactions (excitonic effects) are important to establish a more comprehensive interpretation of photoexcitation dynamics in TMD heterobilayers. However, this is significantly challenging in ab initio calculations because both time-dependent nonequilibrium dynamics and many-body excitonic physics need be accurately captured simultaneously.

In this study, going beyond the IP picture, we discover a *many-body excitonic mechanism*, as an alternative or additional channel, for the dynamics of converting photoexcited intralayer to interlayer excitations and for the associated ultrafast optical responses in TMD heterobilayers. We find that the couplings between the intralayer and interlayer excitonic state induce an ultrafast optical response, conceptually different from the direct single-particle charge transfer channel in the IP picture. Through our *ab initio* time-dependent calculations, strong excitonic effects are shown to play a crucial role on the ultrafast exciton dynamics and the pump-probe optical responses by enhancing the signal by over one-order of magnitude with a rise time about of 300 femtoseconds. To investigate the real-time nonequilibrium dynamics including many-electron interactions and excitonic effects from first-principles, we employ a recently developed *ab initio* time-dependent adiabatic *GW* approach (TD-a*GW*) [26] with real-time propagation of the density matrix in the presence of an external optical field.

In the TD-aGW framework [26],

$$i\hbar \frac{\partial}{\partial t} \rho_{nm,\mathbf{k}}(t) = [H^{aGW}(t), \rho(t)]_{nm,\mathbf{k}},\tag{1}$$

where *n* and *m* are band indices, and $\rho_{nm,k}(t)$ is the density matrix of the interacting manyelectron system in the Bloch-state basis which serves as the key quantity to explore the timedependent field-driven nonequilibrium system. $H_{nm,k}^{aGW}(t)$ is the TD-aGW Hamiltonian defined as:

$$H_{nm,\boldsymbol{k}}^{aGW}(t) = h_{nm,\boldsymbol{k}} + U_{nm,\boldsymbol{k}}^{ext}(t) + \Delta V_{nm,\boldsymbol{k}}^{ee}(t).$$

$$\tag{2}$$

Here, $h_{nm,k}$ is the equilibrium quasi-particle Hamiltonian which includes all the equilibrium interactions (before photoexcitation) at the GW level, and it is independent of time. The external field part is given by $U_{nm,k}^{ext}(t)$ which denotes the light-matter interaction and is equal to $-e\mathbf{E}(t)$. $d_{nm,k}$, where E(t) is the optical electric field and $d_{nm,k}$ is the optical dipole matrix. Importantly, the photo-induced variation of the electron-electron interaction is given by $\Delta V_{nm,k}^{ee}(t)$ which has two parts: $\Delta V_{nm,k}^{ee}(t) = \Delta V_{nm,k}^{H}(t) + \Delta \Sigma_{nm,k}^{COHSEX}(t)$, where the first term is the Hartree potential and the second term is the nonlocal Coulomb hole plus screened-exchange (COHSEX) GW selfenergy taken in the static screening limit which accounts for the time change of the many-electron (quasiparticle and excitonic) effects. In the TD-aGW approach, the excitonic effects is accurately captured at the GW plus Bethe-Salpeter equation (GW-BSE) level [26]. This is validated by the identical linear absorption spectra (Fig. S2 in the Supplemental Material [27]) comparing results from standard GW-BSE calculations with those from TD-aGW. During the real-time evolution, we focus on the photoinduced time variation of the various quantities: $\Delta \rho(t) = \rho(t) - \rho(eq.)$, $\Delta V^{ee}(t) = V^{ee}(t) - V^{ee}(eq.)$, etc., where eq. denote the equilibrium quantities (i.e., in the absence of a time-dependent driving external field). The formalism and computational details on the ab *initio* TD-a*GW* method can be found in the Supplemental Material [27].

Figure 1(a-b) illustrate the theoretical pump-probe setup. We focus on a representative and well studied TMD heterobilayer - MoSe₂/WSe₂ with a common unit cell size of lattice constant 3.30 Å.

As shown in Fig. 1(c), its quasiparticle band structure exhibits a type-II band alignment at the K point (as well as the K' point): the CBM (VBM) is mainly from the MoSe₂ (WSe₂) layer with a quasiparticle bandgap of 1.77 eV. There is very little layer hybridization for states near the K point, consistent with previous work [25]. Fig. 2(a) shows the equilibrium linear optical absorbance of the system, which is computed by solving the *GW*-BSE (computational details are given in Supplemental Material [27]). Without electron-hole interactions, the IP picture fails to capture the main features seen in experiments (not shown) even qualitatively. On the other hand, the results with excitonic effects (red curve) show prominent absorption peaks corresponding to: intralayer MoSe₂ excitons (electron and hole reside on the MoSe₂ layer), intralayer WSe₂ excitons (electron and hole reside on the MoSe₂ and WSe₂, respectively) which have lower energies but weak optical response due to their small optical oscillator strengths.

Next, we investigate the real-time evolution of the interlayer and intralayer exciton states after the system is optically pumped at the MoSe₂ 1s exciton excitation energy (1.79 eV, the first peak in Fig. 2(a)), as shown in Fig. 1(b). In the IP picture, the main dynamics of the system would be that of independent carriers (e.g., photo-induced holes transferring from MoSe₂ layer to WSe₂ layer) through band hybridization or phonon-assisted scatterings. However, for 2D materials, the photoexcited holes are physically not "independent" but bound to the excited electrons forming correlated electron-hole pairs (excitons) with large binding energies (> 300 meV). Therefore, as another channel for the dynamics going beyond the IP picture, we propose a new many-body excitonic picture as shown in Fig. 2(b): after pumping, the excited 1s exciton of MoSe₂ couples to the corelated-continuum (CC) states of the interlayer excited states which are in resonance in energy. Our TD-a*GW* calculations reveal that the dynamical coupling between the photoexcited MoSe₂ intralayer 1s exciton state and the interlayer excitonic continuum states in fact gives rise to a fast and significant time evolution in the system.

The computed real-time dynamics of an averaged photoinduced electron-hole coherence are shown in Fig. 2(c-d). Here we define the averaged electron-hole coherence between two bands $\langle \Delta \rho_{vc}(t) \rangle$ from the change in the off-diagonals of the density matrix as: $\langle \Delta \rho_{vc}(t) \rangle = \frac{1}{N_k} \sum_k |\Delta \rho_{vc,k}(t)|^2$. This quantity provides a measure of the correlation between the electrons and holes in the conduction band *c* and valence band *v*, respectively. As discussed below, the individual k-dependent $\Delta \rho_{vc,k}(t)$ itself is of course the key quantity for determining the measured time-dependent optical responses. As shown in Fig. 2(c), after resonantly pumping at the MoSe₂ 1s exciton excitation energy (1.79 eV), the pump-induced $\langle \Delta \rho_{vc}(t) \rangle$ demonstrates two significant

evolution dynamics: (1) During the pump-pulse duration (marked by the grey shadow in Fig. 2(c), with a full-width-at-half-maximum of 100 fs), the intralayer MoSe₂ exciton is excited. The magnitude of $\Delta \rho_{v_{Mo}c_{Mo}}$ increases dramatically and reaches a maximum at the end of the pump pulse (at about 120 fs). In the upper left panel of Fig. 2(d), at t = 120 fs, a *k*-space distribution analysis reveals that the photoexcited intralayer $\Delta \rho_{v_{Mo}c_{Mo}}(\mathbf{k})$ is centered at *K* point, showing typical 1s exciton features. The lower left panel of Fig. 2(d) indicates a very small interlayer $\Delta \rho_{v_{W}c_{Mo}}(\mathbf{k})$. (2) After the pump pulse ended (>120 fs), the magnitude of $\Delta \rho_{v_{Mo}c_{Mo}}$ shrinks with time along with a growth of the interlayer $\Delta \rho_{v_{W}c_{Mo}}$, demonstrating the excited system is evolving rapidly from one of intralayer exciton character to one with increasing interlayer exciton character. Interestingly, as shown in the lower right panel of Fig. 2(d), the interlayer $\Delta \rho_{v_{W}c_{Mo}}(\mathbf{k})$ is not concentrated at *K* point, reflecting a resonant coupling between the intralayer (MoSe₂) 1s exciton and interlayer correlated-continuum excited states as schematically indicated in Fig. 2(b).

We note that the coherence between holes in different layers ($\Delta \rho_{v_{Mo}v_W}$) is significantly small, therefore a direct valence-to-valence band coupling is negligible, verifying that the single-particle picture of hole transition between valence bands of the two layers is not significant in the ultrafast time scale (Fig. S3 of the Supplemental Material [27]). Very fast phonon-assisted processes are needed if such mechanism is to be viable in the time regime of a few tens to hundreds of femtoseconds.

We now will discuss the driving forces that give rise to the dynamics. In the TD-a*GW* Hamiltonian (Eq. (2)), there are two time-dependent terms: the external field $U^{ext}(t)$ and the internal electron-electron interaction $\Delta V^{ee}(t)$. The latter can be further spitted into two parts: $\Delta V^{H}(t)$ and $\Delta \Sigma^{COHSEX}(t)$, as defined above. In Fig. 3, we compare the real-time evolution of the expectation values of these dynamical terms. Our *ab initio* results show that the $\Delta \Sigma^{COHSEX}(t)$ term which accounts for the excitonic effects is dominant and much larger than the external field term and the Hartree term: the maximum magnitude ratios are $\langle \Delta \Sigma^{COHSEX} \rangle / \langle \Delta V^H \rangle \approx 10$ and $\langle \Delta \Sigma^{COHSEX} \rangle / \langle U^{ext} \rangle \approx 30$, revealing the crucial role of strong excitonic effects. Therefore, excitonic effects is the dominant driving force and must be accurately included in the real-time evolution.

In experiments, the ultrafast pump-induced intralayer-to-interlayer dynamical evolution of the system is measured by an optical pump-probe setup [8] as shown schematically in Fig. 1(b): a much weaker optical pulse is employed to probe one layer (e.g., WSe₂) after a time delay τ from a strong pump pulse on the other layer (e.g., MoSe₂), and the transient probe response signal is

used to investigate the real-time system dynamics. Optically probing the interlayer excitation might offer another way to track the dynamics of interlayer excited states, but typically the very small oscillator strength of the interlayer transitions makes it experimentally impractical (as seen in the extremely weak computed interlayer optical response in Fig. 2(a)). Instead, the WSe₂ 1s exciton (1.90 eV, the second peak in Fig. 2(a)) is optically probed in previous experiments after a pump pulse is used to excite the MoSe₂ 1s exciton (the first peak in Fig. 2(a)). A widely-measured quantity is the transient absorption change $\Delta A/A$ defined as $[A_{pump on}(\tau) - A_{pump off}]/A_{pump off}$, where $A_{pump on}$ and $A_{pump off}$ are absorptions at the probed energy after delay time τ , with and without the pump field [7-11], respectively. In our theoretical study, the transient optical properties are calculated from the polarization P(t) = $\frac{e}{N_k V} \sum_{nm,k} \rho_{nm,k}(t) d_{mn,k}$, where N_k is the number of k points in the BZ sampling and V is the volume of the unit cell. From this expression, it is clear that the optical dynamics is intrinsically related to the dynamics of $\rho_{nm,k}(t)$ discussed above. More details on the calculation of the transient optical absorption from our *ab initio* TD-aGW method are given in the Supplemental Material [27].

As shown in Fig. 4, the computed transient absorption change $\Delta A/A$ (in percents) from TDaGW including excitonic effects exhibits a fast and prominent rise during and immediately after the pump duration (grey shadow in the plot). By fitting to an exponential form $c(1 - e^{-\tau/t_r})$ we extract a theoretical rise time of $t_r \approx 300$ fs, which agrees well with the experimental measurements of about 200 fs [8,13]. On the contrary, in the case of TD-Hartree calculation in which only the Hartree term $\Delta V^{H}(t)$ is included but ignoring excitonic effects from $\Delta \Sigma^{COHSEX}(t)$, there is negligible change in the optical response with the pump pulse: the magnitude is about 30 times smaller than the full TD-aGW case and no discernable rising behavior exists after the pump pulse is subsided, which qualitatively disagree with experiments [8,13]. These results further evidence the key role of excitonic effects on the optical dynamics, which is consistent with the driving forces analysis in Fig. 3. In experiments, existing literature shows that difficult-to-control measurement deviations happen due to variations in relative layer orientation, sample quality, pump-probe details, and other technical issues, leading to a range for the value of the rise time from several tens of fs to hundreds of fs in various TMD heterobilayer samples [7-13]. Moreover, the effects of exciton-phonon coupling which lies outside of the scope of this paper, is expected to bring additional scattering channels into the time evolution [14-19]. As a result, it may also contribute to the rise time which calls for future studies.

In summary, we discover a new many-body excitonic channel for the ultrafast dynamics of photoinduced excited states and optical responses in TMD heterobilayers. Employing a recently developed *ab initio* TD-a*GW* method, we investigate the real-time evolution of the inter-/intra-layer electron-hole coherence, and demonstrate that the couplings between the intralayer 1s exciton states and the interlayer correlated-continuum excited states in a MoSe₂/WSe₂ heterobilayer give rise to real-time excited-state and optical dynamics that are consistent with experiments. The strong excitonic effects in the van der Waals heterobilayers are shown as a major driving force for their excited-state dynamics and ultrafast pump-probe optical responses. The many-body excitonic picture, going beyond the independent-particle theory, thus provides new insights to the ultrafast optoelectronics in TMD heterostructures.

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References

[1] B. Hunt et al., Massive Dirac fermions and Hofstadter butterfly in a van der Waals heterostructure, Science 340,1427 (2013)

- [2] Q. Tong, H. Yu, Q. Zhu, Y. Wang, X. Xu, and W. Yao, Topological mosaics in moire superlattices of van der Waals heterobilayers, Nat. Phys. 13, 356 (2017)
- [3] C. Hu, V. Michaud-Rioux, W. Yao, and H. Guo, Moiré Valleytronics: Realizing Dense Arrays of Topological Helical Channels, Phys. Rev. Lett. 121, 186403 (2018)
- [4] Y. Cao, V. Fatemi, S. Fang, K. Watanabe, T. Taniguchi, E. Kaxiras, and P. Jarillo-Herrero, Unconventional superconductivity in magic-angle graphene superlattices, Nature 556, 43 (2018)
- [5] Y. Cao et al., Correlated insulator behaviour at half-filling in magic-angle graphene superlattices, Nature 556,80 (2018)
- [6] G. Wang, A. Chernikov, M. M. Glazov, T. F. Heinz, X. Marie, T. Amand, and B. Urbaszek, Colloquium: Excitons in atomically thin transition metal dichalcogenides, Rev. Mod. Phys. 90, 021001 (2018)
- [7] C. Jin, E. Y. Ma, O. Karni, E. C. Regan, F. Wang, and T. F. Heinz, Ultrafast dynamics in van der Waals heterostructures, Nat. Nanotech. 13, 994 (2018)
- [8] Z. Wang et al., Phonon-Mediated Interlayer Charge Separation and Recombination in a MoSe₂/WSe₂ Heterostructure, Nano Lett. 21, 2165 (2021)
- [9] X. Hong et al., Ultrafast charge transfer in atomically thin MoS₂/WS₂ heterostructures, Nat. Nanotech. 9, 682 (2014)
- [10] H. Zhu, J. Wang, Z. Gong, Y. D. Kim, J. Hone, and X.Y. Zhu, Interfacial Charge Transfer Circumventing Momentum Mismatch at Two-Dimensional van der Waals Heterojunctions, Nano Lett. 17, 3591 (2017)
- [11] F. Ceballos et al., Ultrafast charge separation and indirect exciton formation in a MoS₂-MoSe₂ van der Waals heterostructure. ACS Nano 8, 12717 (2014)
- [12] J. E. Zimmermann et al., Ultrafast Charge-Transfer Dynamics in Twisted MoS₂/WSe₂ Heterostructures, ACS Nano 15, 14725 (2021)
- [13] J. E. Zimmermann et al., Directional ultrafast charge transfer in a WSe₂/MoSe₂ heterostructure selectively probed by time-resolved SHG imaging microscopy, Nanoscale Horiz. 5, 1603 (2020)
- [14] H. Wang, J. Bang, Y. Sun, L. Liang, D. West, V. Meunier, and S. Zhang, The role of collective motion in the ultrafast charge transfer in van der Waals heterostructures, Nat. Commun. 7, 11504 (2016)
- [15] Q. Zheng, Y. Xie, Z. Lan, O. V. Prezhdo, W. A. Saidi, and J. Zhao, Phonon-coupled ultrafast interlayer charge oscillation at van der Waals heterostructure interfaces, Phys. Rev. B 97, 205417 (2018)
- [16] Q. Zheng, W. A. Saidi, Y. Xie, Z. Lan, O. V. Prezhdo, H. Petek, and J. Zhao, Phonon-assisted ultrafast charge transfer at van der Waals heterostructure interface, Nano Lett. 17, 6435 (2017)
- [17] J. Zhang, H. Hong, C. Lian, W. Ma, X. Xu, X. Zhou, H. Fu, K. Liu, and S. Meng, Interlayer-State-Coupling Dependent Ultrafast Charge Transfer in MoS₂/WS₂ Bilayers, Adv. Sci. 4,1700086 (2017)
- [18] Run Long and O. V. Prezhdo, Quantum Coherence Facilitates Efficient Charge Separation at a MoS₂/MoSe₂ van der Waals Junction, Nano Lett. 16, 1996 (2016)
- [19] J. Liu, X. Zhang, and G. Lu, Excitonic Effect Drives Ultrafast Dynamics in van der Waals Heterostructures, Nano Lett. 20, 4631 (2020)

- [20] D. Y. Qiu, F. H. da Jornada, and S. G. Louie, Optical spectrum of MoS₂: Many-body effects and diversity of exciton states, Phys. Rev. Lett. 111, 216805 (2013)
- [21] D. Y. Qiu, F. H. da Jornada, and S. G. Louie, Environmental screening effects in 2D materials: Renormalization of the bandgap, electronic structure, and optical spectra of few-layer black phosphorus, Nano Lett. 17, 4706 (2017)
- [22] M. Wu, Z. Li, T. Cao, and S. G. Louie, Physical origin of giant excitonic and magnetooptical responses in two-dimensional ferromagnetic insulators, Nat. Commun. 10, 2371 (2019)
- [23] M. Wu, Z. Li, and S. G. Louie, Optical and magneto-optical properties of ferromagnetic monolayer CrBr: A first-principles GW and GW plus Bethe-Salpeter equation study, Phys. Rev. Mater. 6, 014008 (2022)
- [24] F. Zhang, C. S. Ong, J. Ruan, M. Wu, X. Q. Shi, Z. K. Tang, and S. G Louie, Intervalley Excitonic Hybridization, Optical Selection Rules, and Imperfect Circular Dichroism in Monolayer h-BN, Phys. Rev. Lett. 128, 047402 (2022)
- [25] X. Lu, X. Li, and L. Yang, Modulated interlayer exciton properties in a two-dimensional moiré crystal, Phys. Rev. B 100, 155416 (2019)
- [26] Y.-H. Chan, D. Y. Qiu, F. H. da Jornada, and S. G. Louie, Giant exciton-enhanced shift currents and direct current conduction with subbandgap photo excitations produced by many-electron interactions, Proc. Natl. Acad. Sci. USA 118, e1906938118 (2021)
- [27] See Supplemental Material for (1) computational details (DFT, GW-BSE and TD-aGW), (2) geometric configuration of the MoSe₂/WSe₂ heterobilayer, (3) comparison of optical absorbances computed from TD-aGW and GW-BSE, and (4) hole-hole coherence dynamics, which includes Refs. [28-42]
- [28] P. Giannozzi et al., QUANTUM ESPRESSO: A modular and open-source software project for quantum simulations of materials, J. Phys. Condens. Matter 21, 395502 (2009)
- [29] M. S. Hybertsen and S. G. Louie, Electron correlation in semiconductors and insulators: Band gaps and quasiparticle energies, Phys. Rev. B 34, 5390 (1986)
- [30] M. Rohlfing and S. G. Louie, Electron-hole excitations in semiconductors and insulators, Phys. Rev. Lett. 81, 2312 (1998)
- [31] M. Rohlfing and S. G. Louie, Electron-hole excitations and optical spectra from first principles, Phys. Rev. B 62, 4927 (2000)
- [32] J. Deslippe, G. Samsonidze, D. A. Strubbe, M. Jain, M. L. Cohen, and S. G. Louie, BerkeleyGW: A massively parallel computer package for the calculation of the quasiparticle and optical properties of materials and nanostructures, Comput. Phys. Commun. 183, 1269 (2012)
- [33] D. R. Hamann, Optimized norm-conserving Vanderbilt pseudopotentials, Phys. Rev. B 88, 085117 (2013)
- [34] J. P. Perdew, K. Burke, and M. Ernzerhof, Generalized gradient approximation made simple. Phys. Rev. Lett. 77, 3865 (1996)
- [35] F. H. da Jornada, D. Y. Qiu, and S. G. Louie, Nonuniform sampling schemes of the Brillouin zone for many-electron perturbation-theory calculations in reduced dimensionality, Phys. Rev. B 95, 035109 (2017)
- [36] L. P. Kadanoff, and G. Baym, Quantum Statistical Mechanics (W. A. Benjamin, Inc., 1962)

- [37] C. Attaccalite, M. Grüning, and A. Marini, Real-time approach to the optical properties of solids and nanostructures: Time-dependent Bethe-Salpeter equation, Phys. Rev. B 84, 245110 (2011)
- [38] L. Yang, J. Deslippe, C.-H. Park, M. L. Cohen, and S. G. Louie, Excitonic effects on the optical response of graphene and bilayer graphene, Phys. Rev. Lett. 103, 186802 (2009)
- [39] M. L. Cohen and S. G. Louie, Fundamentals of condensed matter physics (Cambridge University Press, 2016)
- [40] D. Sangalli, Excitons and carriers in transient absorption and time-resolved ARPES spectroscopy: An ab initio approach, Phys. Rev. Mater. 5, 083803 (2021)
- [41] D. Sangalli, S. Dal Conte, C. Manzoni, G. Cerullo, and A. Marini, Nonequilibrium optical properties in semiconductors from first principles: A combined theoretical and experimental study of bulk silicon, Phys. Rev. B 93, 195205 (2016)
- [42] E. Perfetto, D. Sangalli, A. Marini, and G. Stefanucci, Nonequilibrium Bethe-Salpeter equation for transient photoabsorption spectroscopy, Phys. Rev. B 92, 205304 (2015)

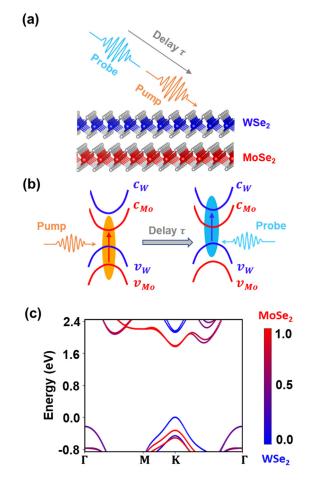


Fig. 1: (a-b) Schematic of the ultrafast optical pump-probe setup for study of MoSe₂/WSe₂ heterobilayers with a type II band alignment. The delay time τ denotes the time separation between the pump pulse and the probe pulse. Optically-pumped excitation of 1s exciton in the MoSe₂ layer leads to the ultrafast inter-layer dynamics which is probed by an optical pulse with WSe₂ 1s exciton excitation energy after different time delay τ . c_W , c_{Mo} , v_W , v_{Mo} denote the conduction band of WSe₂ and MoSe₂, and the valence band of WSe₂ and MoSe₂, respectively. (c) *GW* quasiparticle band structure. The energy of the top of valence band of the bilayer is set to be zero. The color represents the layer-component projection of each Bloch state to the different layers.

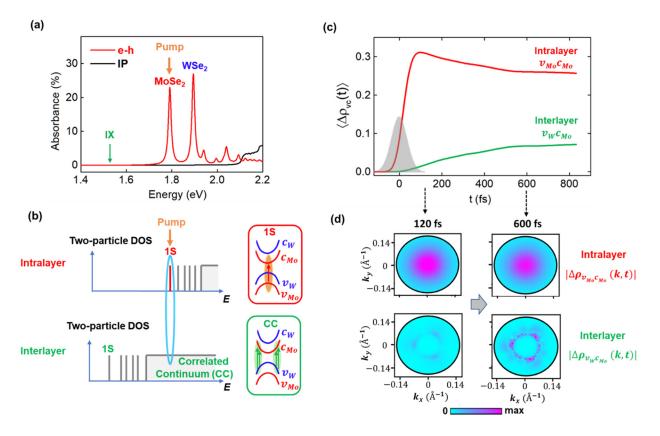


Fig. 2: (a) Absorbance of the MoSe₂/WSe₂ heterobilayer computed with (*e*-*h*, red solid line) and without (IP, black dashed line) electron-hole interactions. The position of the lowest-energy optically active interlayer exciton (IX) is marked by the green arrow. (b) Schematic of coupling between intralayer (MoSe₂) 1s exciton and interlayer correlated-continuum (CC) excited states, indicated by the two-particle (correlated electron-hole pair) density of states (DOS). (c) Pump-induced real-time evolution of electron-hole coherence, as seen through an average of the photoinduced variations of the density matrix off-diagonals: $\langle \Delta \rho_{vc}(t) \rangle = \frac{1}{N_k} \sum_k |\Delta \rho_{vc,k}(t)|^2$, where intralayer (red line) and interlayer (green line) quantities are given by taking $vc = v_{Mo}c_{Mo}$ and $v_W c_{Mo}$ respectively. The grey shadow area shows the pump-pulse intensity duration in time (Gaussian shape). We set the center of the pump pulse as zero of the time line. (d) *k*-space distributions of intralayer and interlayer electron-hole coherence magnitudes $|\Delta \rho_{vc}(k,t)|$ at two representative time points: snapshot at 120 femtoseconds (fs) and at 600 femtoseconds (fs) after the pump pulse, showing significant interlayer dynamics. In the plot, the *K* point is set as the origin for clarity.

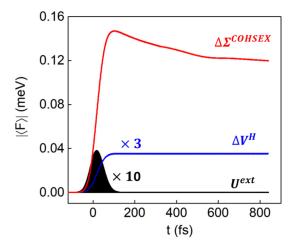


Fig. 3: Real-time evolution of various terms in the TD-a *GW* effective Hamiltonian. The expectation values of time dependence of different dynamical terms are defined as $\langle F(t) \rangle = Tr\{\rho(t)F(t)\}$, where *F* is the external optical pump field (U^{ext} , black line), pump-induced Hartree potential variation (ΔV^H , blue line), or pump-induced many-body COHSEX self-energy variation ($\Delta \Sigma^{COHSEX}$, red line).

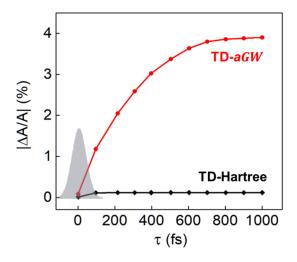


Fig. 4: Computed transient optical response as function of pump-probe delay time τ , as schematically depicted in Fig. 1(b). The black and red lines present the TD-a*GW* and TD-Hartree results, which are time evolutions with and without excitonic effects (*i.e.*, many-body $\Delta\Sigma^{COHSEX}(t)$ term) included, respectively. The grey shadow area shows the pump-pulse intensity duration in time (Gaussian shape).

Supplemental Material for "Excitonic interactions and mechanism for ultrafast interlayer photoexcited response in van der Waals heterostructures"

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In this Supplemental Material, we provide some detailed computational information and further results. We organize the material into the following sections:

- 1. Computational details of DFT calculations, *GW*-BSE calculations, and TD-a*GW* calculations;
- 2. Geometric configuration of the MoSe₂/WSe₂ heterobilayer;
- 3. Comparison of optical absorbances computed from TD-aGW and GW-BSE;
- 4. Hole-hole coherence dynamics.

I. Computational details

The workflow of this work involves three main computation steps: (1) Calculations of groundstate properties based on density functional theory (DFT) with the Quantum Espresso package [28]; (2) Calculations of equilibrium quasiparticle states based on the GW method [29] and of excitons and optical properties based on the *GW* plus Bethe-Salpeter equation (*GW*-BSE) approach [30,31] with the Berkeley*GW* package [32]; (3) Calculations of real-time nonequilibrium excited-state dynamics and transient optical response based on the time-dependent adiabatic *GW* (TD-a*GW*) approach [26].

(A) DFT calculation

In this work, the mean-field DFT calculations are performed with the Quantum Espresso package [28]. We use Optimized Norm-Conserving Vanderbilt (ONCV) pseudopotentials [33] with PBE to the exchange-correlation functional [34], and a plane-wave basis with an energy cutoff of 80 Ry. The structure is fully optimized by minimizing the forces on the atoms with van der Waals (vdW) interactions. The optimized lattice constant is 3.30 Å and the interlayer distance (metal atom to metal atom) is 6.50 Å. The optimized atomic structure is shown in Fig. S1. The full spinor formalism with spin-orbital coupling is employed in the DFT calculations.

(B) GW-BSE calculation

The *GW* and *GW*-BSE calculations are performed with the Berkeley*GW* package [29-32]. For the *GW* calculations (at the G₀W₀ level) on the quasiparticle energies, a total of 6000 bands and a 35 Ry cutoff are included. We use a $6 \times 6 \times 1$ *k*-grid with 10 subsampling points within the nonuniform neck subsampling (NNS) method to describe the 2D dielectric screening [35]. The dynamical screening is treated by using the Hybertsen-Louie generalized plasmon pole model [29].

For the *GW*-BSE calculations on excitons and optical absorption, a very fine *k*-point sampling of $210 \times 210 \times 1$ is taken to well capture the properties of the correlated-continuum. A full interacting kernel is employed both in the BSE and TD-a*GW* calculations. The spin-orbital coupling of TMD monolayers or heterobilayers is known to give rise to two split exciton series (A and B) with large energy separations (>200 meV in the MoSe₂/WSe₂ system we studied) and negligible mixing between them [20]. As a result, despite that we include spin-orbital coupling in all calculations (DFT, *GW*-BSE, TD-a*GW*), only the lower-energy A series is focused in our discussions and analysis (consistent with experimental studies [8]). In the optical absorption plot [Fig. 2(a) of the main text], a Lorentzian broadening factor of 7 meV is used.

(C) TD-aGW calculation

A general approach to solve interacting quantum many-body systems in nonequilibrium is the Kadanoff-Baym equations (KBE) approach, which describes the equations of motion for the interacting Green's function G on the Keldysh contour C [36]:

$$i\frac{d}{dt}G(t,t') = \delta(t,t') + [H_0 + U^{ext}(t)]G(t,t') + \int_C \Sigma(t,t'')G(t'',t')dt'' , \qquad (S1)$$

where H_0 is the static equilibrium Hamiltonian, $U^{ext}(t)$ denotes the interaction with an external field, G is the contour-ordered Green's function, and Σ is the electron self-energy operator. A complete set of KBE should combine Eq. S1 with another equivalent adjoint equation of propagating t'. Direct solutions for the KBE need the treatment of two coupled time variables t and t', which gives rise to tremendous computational burden for time propagating real material systems to a measurable duration (*e.g.*, several hundreds of fs in ultrafast experiments). A practical and effective approach we adopted is the adiabatic GW (aGW) approximation [26,37], where an instantaneous self-energy (time-diagonal t = t'), *i.e.*, in the static Coulomb hole plus screened-exchange (COHSEX) [32] limited, is employed.

Within the TD-a*GW* approach, the KBE in Eq. S1 can be rigorously expressed as the equation of motion of the density matrix in Eq. 1 of the main text [26,37]. In our calculations, a Bloch orbital basis is used: $O_{nm,k} = \langle n\mathbf{k} | \hat{O} | m\mathbf{k} \rangle$, where $|n\mathbf{k} \rangle$ and $|m\mathbf{k} \rangle$ are Bloch eigenstates, and \hat{O} is the physical quantity operator of interest, for example, the density matrix ρ , self-energy Σ , *etc.* As shown in the TD-a*GW* formalism (Eq. 1 of the main text), at equilibrium, all interactions and information are included in the $h_{nm,k}$ term (the equilibrium quasi-particle energies which are independent of time); therefore, during the time evolution, we only need to focus on the fieldinduced variation of the quantities: $\Delta \rho_{nm,k}(t) = \rho_{nm,k}(t) - \rho_{nm,k}(eq.)$, $\Delta V_{nm,k}^{ee}(t) = V_{nm,k}^{ee}(t) - V_{nm,k}^{ee}(eq.)$, *etc.*, where *eq.* denotes the equilibrium case. In the Bloch state basis of the TD-a*GW* approach, excitonic effects are included through $\Delta \Sigma_{nm,k}^{COHSEX}(t)$ as:

$$\Delta \Sigma_{nm,\mathbf{k}}^{COHSEX}(t) = i \sum_{n'm',\mathbf{k}'} \Delta G_{n'm',\mathbf{k}'}^{<}(t) \ W_{m\mathbf{k},m'\mathbf{k}';\,n\mathbf{k},n'\mathbf{k}'} , \qquad (S2)$$

where $G_{n'm',k'}^{<}(t)$ is the time-diagonal of the lesser Green's function and we have $\rho_{nm,k}(t) = -iG_{nm,k}^{<}(t)$. W is the statically screened Coulomb potential as used in standard formulation of the interacting kernel of the BSE Hamiltonian. It is proved that by employing the $\Delta \Sigma_{nm,k}^{COHSEX}(t)$ with TD-aGW, one can capture the many-body excitonic effects (electron-hole interaction) in linear

optical processes at the GW-BSE level [26,37], which is evidenced by the identical linear absorption spectra from the TD-aGW method and GW-BSE method as shown in Fig. S2.

The optical properties in the TD-aGW framework are calculated from the optical-induced (probe-induced) polarization variation:

$$\Delta \boldsymbol{P}(t) = \frac{e}{N_k V} \sum_{nm,k} \Delta \rho_{nm,k}(t) \, \boldsymbol{d}_{mn,k} \,, \qquad (S3)$$

where N_k is the number of k points, V is the volume of the unit cell, and $d_{mn,k}$ is the optical dipole matrix. The linear optical absorption $A(\omega)$ is intrinsically related to the imaginary part of firstorder optical susceptibility $Im[\chi(\omega)]$ by: $A(\omega) = 1 - e^{-A_0(\omega)}$ and $A_0(\omega) = \omega dIm[\chi(\omega)]/c$, where d is the thickness of the 2D supercell and c is the speed of light in vacuum [38,39]. The first-order optical susceptibility $\chi(\omega)$ can be calculated from the Fourier transformations of the optical field E(t) and its induced polarization $\Delta P(t)$ as:

$$\Delta P(\omega) = \varepsilon_0 \chi(\omega) E(\omega), \qquad (S4)$$

where ε_0 is the permittivity of vacuum. The probe-induced transient optical response is computed from the probe-induced variation of the polarization of the system, which depends on the delay time τ of the probe pulse. We follow the scheme described in Refs. [40-42].

In our TD-a*GW* calculations, the time propagation is performed with a time step of 0.0048 fs using a fourth order Runge-Kutta method. Two valence band and two conduction band $(c_{Mo}, c_W, v_{Mo}, v_W)$ are included in the simulations. We employ a very fine **k** sampling 210 × 210 × 1 of the Brillouin zone to well capture the properties of the correlated-continuum (consistent with the BSE interacting kernel). The intensity of the pump field is taken as $1.0 \times 10^7 W/cm^2$, to excite a total carrier (electron or hole) density of about $5 \times 10^{11} cm^{-2}$, consistent with the order of magnitude in usual experimental setups [9,12]. The intensity of the probe field is taken as 10^{-5} that of the pump field so it has negligible effect on the pump-induced dynamics. The pump-pulse field is taken as a Gaussian shape in time with the full width at half-maximum (FWHM) of 100 fs.

II. Geometric configuration

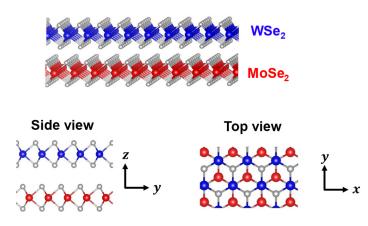


Fig. S1: Atomic structure of the optimized MoSe₂/WSe₂ bilayer.

The atomic structure (energy-favorable stacking configuration) of MoSe₂/WSe₂ is fully optimized by minimizing the forces on atoms with vdW interactions. MoSe₂ and WSe₂ have negligible lattice constant mismatch (<0.1%). Thus, in this study, the lattice constants of the two layers are taken to be the same and relaxed. The purple, light blue and green balls represent Mo, W and Se atoms, respectively. The optimized lattice constant is 3.30 Å and the interlayer distance (metal atom to metal atom) is 6.50 Å.

III. Comparison of optical absorbances from TD-aGW and GW-BSE

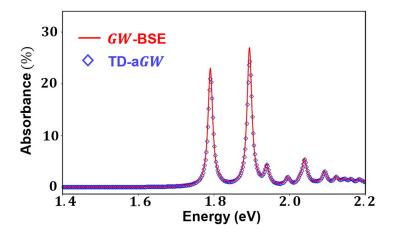


Fig. S2: Linear optical absorbance from GW-BSE (red line) and TD-aGW (blue dimond).

As discussed in the main text and Section 1C of this Supplemental Material, the many-body excitonic effects (electron-hole interactions) in the TD-aGW is equivalent to that of GW-BSE in the linear optical response. As a result, they give identical linear absorbance spectra as shown in Fig. S2.

IV. Hole-hole coherence dynamics

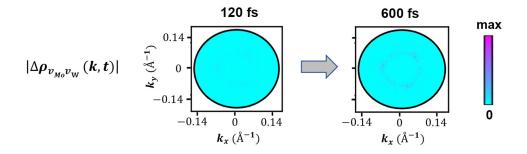


Fig. S3: **k**-distributions of hole-hole coherence dynamics: $\Delta \rho_{v_{Mo}v_W}(\mathbf{k}, t)$ at t = 120 fs and 600 fs. The magnitude is plotted, and the same color bar is used as in Fig. 2(d) of the main text.

In the main text, the dynamics of the interlayer and intralayer electron-hole coherences have been investigated. Here we will discuss the coherence between holes in different layers which is characterized by $\Delta \rho_{\nu_{Mo}\nu_W}$ (\mathbf{k}, t). Comparing Fig. S3 and Fig. 2(d) of the main text, we find that the magnitude and dynamics of hole-hole coherence are significantly smaller than those of electron-hole coherences. Therefore, the direct valence-valence band transition from one layer to anther is negligible for this system, and single-particle hole transitions without phonon assistance between valence bands are in fact not a significant contribution to the dynamics of interest.